

## DRV2511-Q1 8-A Automotive Haptic Driver for Solenoids and Voice Coils

### 1 Features

- Wide Operating Voltage (4.5 V - 26 V)
- Capable of handling voltage of 30 V
- High Current Drive (8 A Peak)
- Low  $R_{DS(on)}$ , Full H-Bridge Output
- Integrated Fault Protection
  - Short-Circuit Protection
  - Over-temperature Protection
  - Over-Voltage and Under-Voltage Protection
  - Fault Reporting
- Analog Input
- Dedicated Interrupt Pin
- AEC-Q100 Qualified with the Following Results:
  - Device Temperature Grade 1:  $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$  Ambient Operating Temperature Range
  - Device HBM ESD Classification Level H2
  - Device CDM ESD Classification Level C4B

### 2 Applications

- Electromagnetic Actuator Driver
  - Voice Coil
  - Solenoid
- Mechanical Button Replacement
- Automotive Haptic Applications
  - Infotainment
  - Center-Console
  - Steering Wheel
  - Door-Panel
  - Seats

### 3 Description

The DRV2511-Q1 device is a high current haptic driver specifically designed for inductive loads, such as solenoids and voice coils.

The output stage consists of a full H-bridge capable of delivering 8 A of peak current.

The DRV2511-Q1 device provides protection functions such as undervoltage lockout, over-current protection and over-temperature protection.

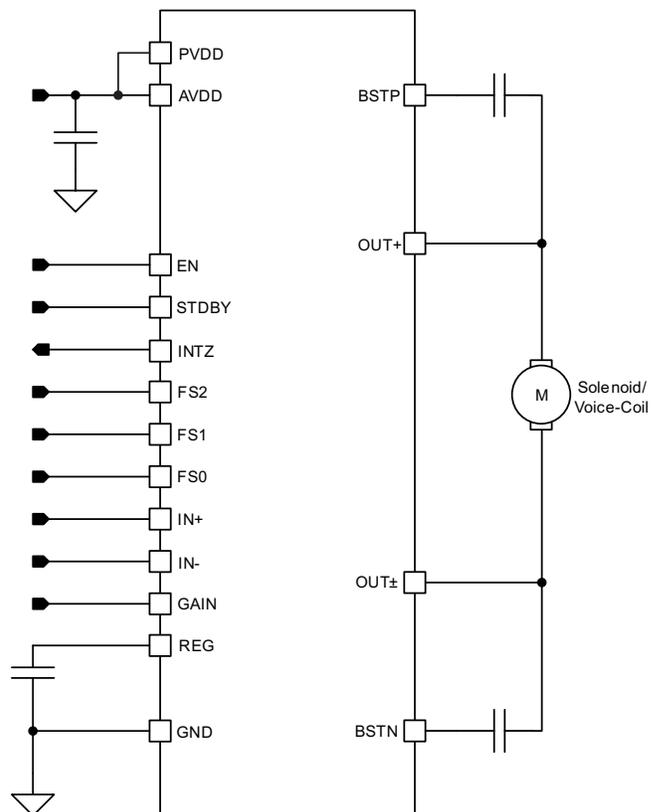
The DRV2511-Q1 device is automotive qualified.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
DRV2511-Q1	HTSSOP (32)	11 mm x 6.20 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

#### Simplified Schematic



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## 4 Revision History

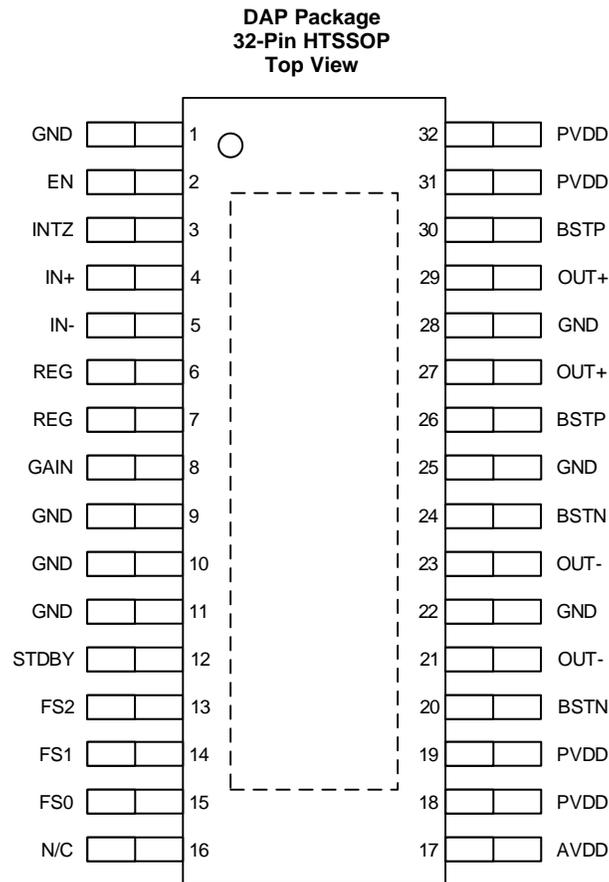
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

### Changes from Original (June 2016) to Revision A

Page

• Released as Production Data. ....	<b>1</b>
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## 5 Pin Configuration and Functions



### Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
GND	1, 9, 10, 11, 22, 25, 28	P	Ground.
EN	2	I	Device enable pin.
INTZ	3	O	General fault reporting. Open drain. INTZ = High, normal operation INTZ = Low, fault condition
IN+	4	I	Positive differential input.
IN-	5	I	Negative differential input.
REG	6, 7	P	Internally generated gate voltage supply. Not to be used as a supply or connected to any component other than a 1 $\mu$ F X7R ceramic decoupling capacitor and the MODE resistor divider.
GAIN	8	I	Selects Gain.
STDBY	12	I	Standby pin.
FS2	13	I	Output switching frequency selection.
FS1	14	I	Output switching frequency selection.
FS0	15	I	Output switching frequency selection.
N/C	16	N/C	Pin should be left floating.
AVDD	17	P	Analog Supply, can be connected to VBAT for single power supply operation.
PVDD	18, 19, 31, 32	P	Power supply.
BSTN	20, 24	P	Boot strap for negative output, connect to 220 nF X5R, or better ceramic cap to OUT-.
OUT-	21, 23	O	Negative output.
BSTP	26, 30	P	Boot strap for positive output, connect to 220 nF X5R, or better ceramic cap to OUT+.

### Pin Functions (continued)

PIN		TYPE	DESCRIPTION
NAME	NO.		
OUT+	27, 29	O	Positive output.
Thermal Pad or PowerPAD™		G	Connect to GND for best system performance. If not connected to GND, leave floating.

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) <sup>(1)</sup>

		MIN	MAX	UNIT
Supply voltage	PVDD, AVDD	-0.3	30	V
Input voltage, $V_I$	IN+, IN-	-0.3	6.3	V
	GAIN	-0.3	VREG + 0.3	
	EN	-0.3	PVDD + 0.3	
Current	DC current on PVDD, GND, OUT+, OUT-	-8	8	A
Operating free-air temperature, $T_A$		-40	125	°C
Storage temperature range, $T_{stg}$		-50	150	

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 6.2 ESD Ratings

		MIN	MAX	UNIT
$V_{(ESD)}$ Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>	-2000	2000	V
	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup>	-450	450	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.  
 (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
VDD	Supply voltage. PVDD, AVDD.	4.5		26	V
$V_{IH}$	High-level input voltage. STDBY, EN, FS0, FS1, FS2.	2			V
$V_{IL}$	Low-level input voltage. STDBY, EN, FS0, FS1, FS2.			0.8	V
$V_{OL}$	Low-level output voltage. INTZ, $R_{PULL-UP} = 100\text{ k}\Omega$ , PVDD = 26 V.			0.8	V
$I_{IH}$	High-level input current. STDBY, EN, FS0, FS1, FS2. ( $V_I = 2\text{ V}$ , PVDD = 26 V).			50	$\mu\text{A}$
$R_L$	Minimum load Impedance.		1.65		$\Omega$
$L_o$	Output-filter Inductance.	1			$\mu\text{H}$

### 6.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		DRV2511-Q1	UNIT
		DAP	
		32 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	32.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	17.2	°C/W

- (1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](http://SPRA953).

**Thermal Information (continued)**

THERMAL METRIC <sup>(1)</sup>		DRV2511-Q1	UNIT
		DAP	
		32 PINS	
$R_{\theta JB}$	Junction-to-board thermal resistance	17.3	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	0.4	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	17.2	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	1	°C/W

## 6.5 Electrical Characteristics

 $T_A = 25^\circ\text{C}$ ,  $AV_{CC} = PV_{DD} = 12\text{ V}$ ,  $R_L = 5\ \Omega$  (unless otherwise noted)

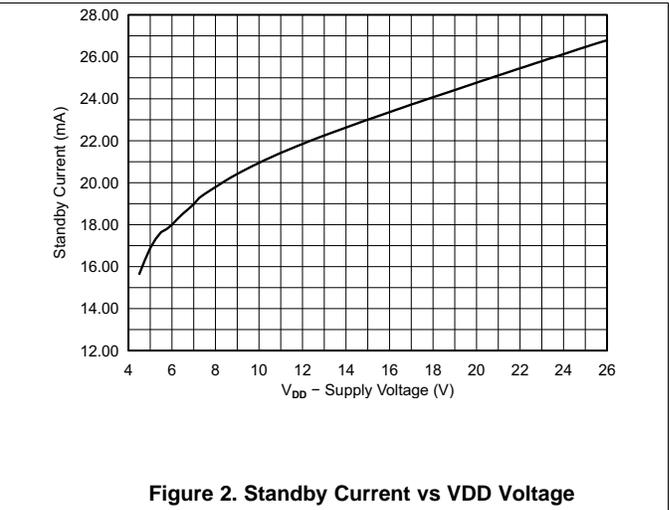
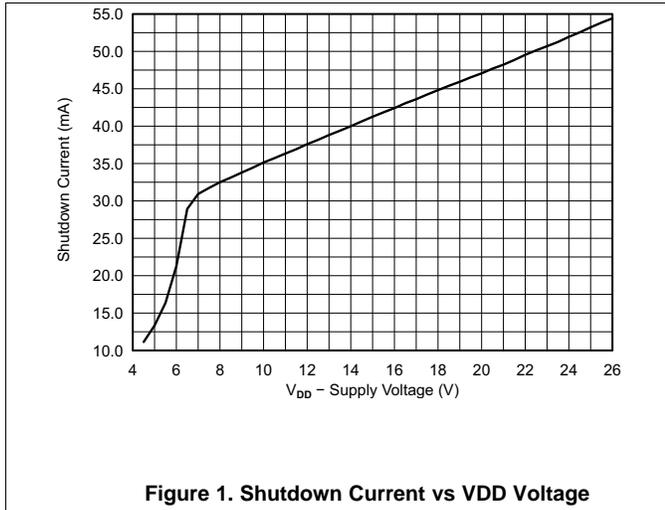
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$ V_{OS} $	Output offset voltage (measured differentially)	$V_I = 0\text{ V}$ , Gain = 36 dB		1.5	15	mV
$I_{VDD}$	Quiescent supply current	No load or filter		20		mA
$I_{VDD(SD)}$	Quiescent supply current in shutdown mode	No load or filter		35		$\mu\text{A}$
$I_{VDD(STD BY)}$	Quiescent supply current in standby mode	No load or filter		11		mA
$r_{DS(on)}$	Drain-source on-state resistance, measured pin to pin	$T_J = 25^\circ\text{C}$		60		$\text{m}\Omega$
G	Gain	$R1 = \text{open}$ , $R2 = 20\ \text{k}\Omega$	19	20	21	dB
		$R1 = 100\ \text{k}\Omega$ , $R2 = 20\ \text{k}\Omega$	25	26	27	
		$R1 = 100\ \text{k}\Omega$ , $R2 = 39\ \text{k}\Omega$	31	32	33	dB
		$R1 = 75\ \text{k}\Omega$ , $R2 = 47\ \text{k}\Omega$	35	36	37	
$V_{REG}$	Regulator voltage		6.4	6.9	7.4	V
BW	Full Power Bandwidth			60		kHz
$V_O$	Output voltage (measured differentially)	Measured at $PV_{DD} = 26\text{V}$		50		V
PSRR	Power supply ripple rejection	200 mVpp ripple at 1 kHz, Gain = 20 dB		-70		dB
CMRR	Common-mode rejection ratio			-56		dB
$f_{OSC}$	Oscillator frequency (with PWM duty cycle < 96%)	FS2 = 0, FS1 = 0, FS0 = 0	376	400	424	kHz
		FS2 = 0, FS1 = 0, FS0 = 1	470	500	530	
		FS2 = 0, FS1 = 1, FS0 = 0	564	600	636	
		FS2 = 0, FS1 = 1, FS0 = 1	940	1000	1060	
		FS2 = 1, FS1 = 0, FS0 = 0	1128	1200	1278	
	Power-on threshold		4.1			V
	Power-off threshold		28			V
	Thermal trip point		150			$^\circ\text{C}$
	Thermal hysteresis		15			$^\circ\text{C}$
	Over-current trip point		13			A
	Over-voltage trip point		28			V

## 6.6 Switching Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{on-sd}$	Turn-on time from shutdown to waveform	EN = Low to High, STBY = Low		10		ms
$t_{OFF-sd}$	Turn-off time	EN = High to Low		5		$\mu\text{s}$
$t_{on-stdby}$	Turn-on time from standby to waveform	EN = High, STBY = High to Low		6		$\mu\text{s}$

## 6.7 Typical Characteristics



## 7 Detailed Description

### 7.1 Overview

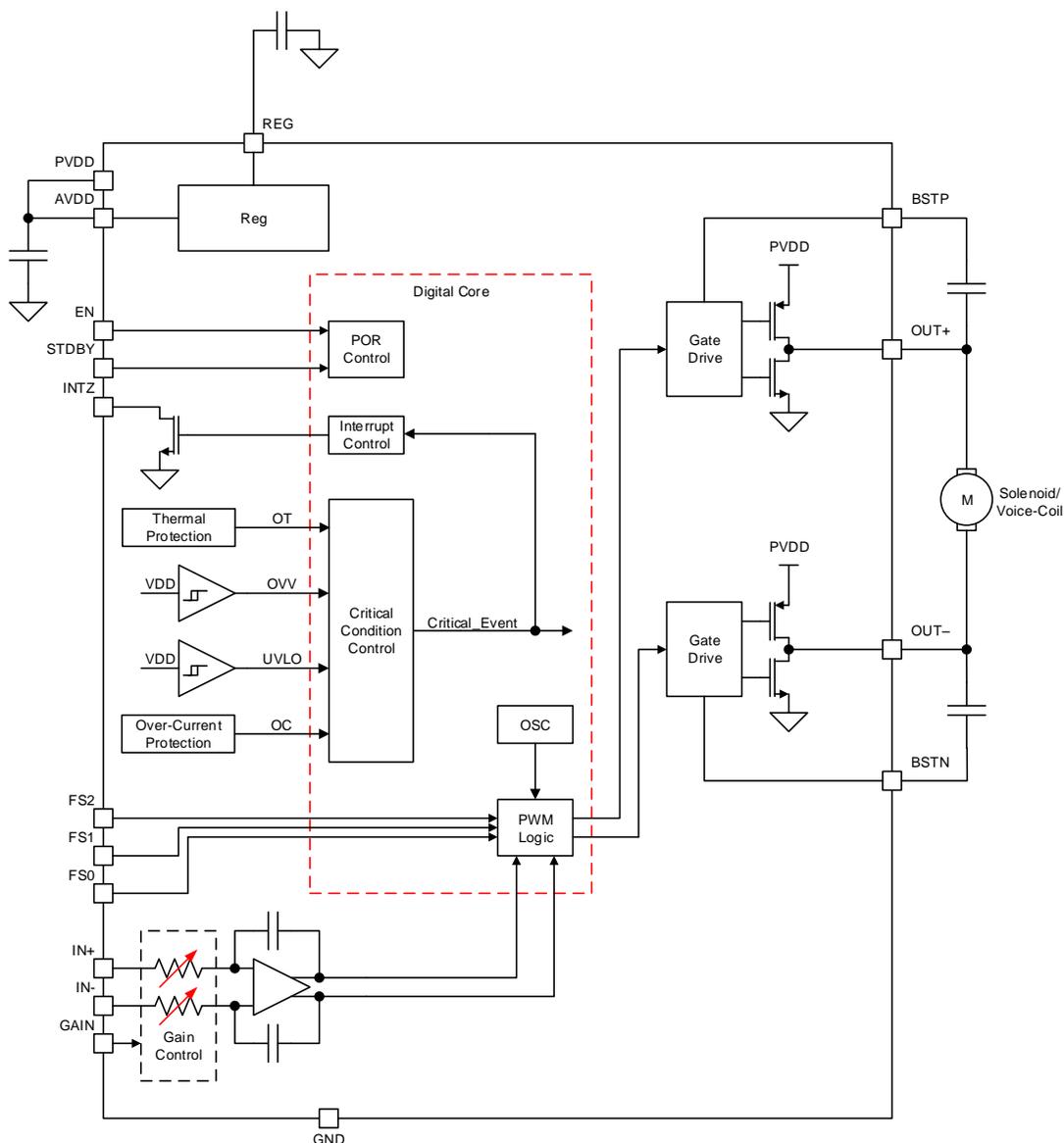
The DRV2511-Q1 device is a high current haptic driver specifically designed for inductive loads, such as solenoids and voice coils.

The output stage consists of a full H-bridge capable of delivering 8 A of peak current.

The design uses an ultra-efficient switching output technology developed by Texas Instruments, but with features added for the automotive industry. The DRV2511-Q1 device provides protection functions such as undervoltage lockout, over-current protection and over-temperature protection. This technology allows for reduced power consumption, reduced heat, and reduced peak currents in the electrical system.

The DRV2511-Q1 device is automotive qualified.

### 7.2 Functional Block Diagram



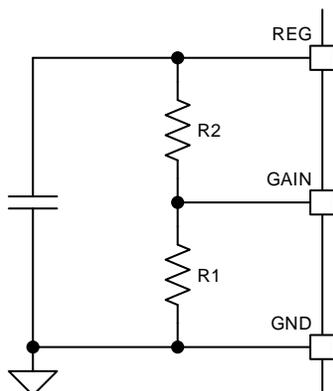
## 7.3 Feature Description

### 7.3.1 Analog Input and Configurable Pre-amplifier

The DRV2511-Q1 device features a differential input stage that cancels common-mode noise that appears on the inputs. The DRV2511-Q1 device also features four gain settings that are configurable via external resistors.

**Table 1. Gain Configuration Table**

GAIN	R1	R2	INPUT IMPEDANCE
20 dB	5.6 k $\Omega$	open	60 k $\Omega$
26 dB	20 k $\Omega$	100 k $\Omega$	30 k $\Omega$
32 dB	39 k $\Omega$	100 k $\Omega$	15 k $\Omega$
36 dB	47 k $\Omega$	75 k $\Omega$	9 k $\Omega$

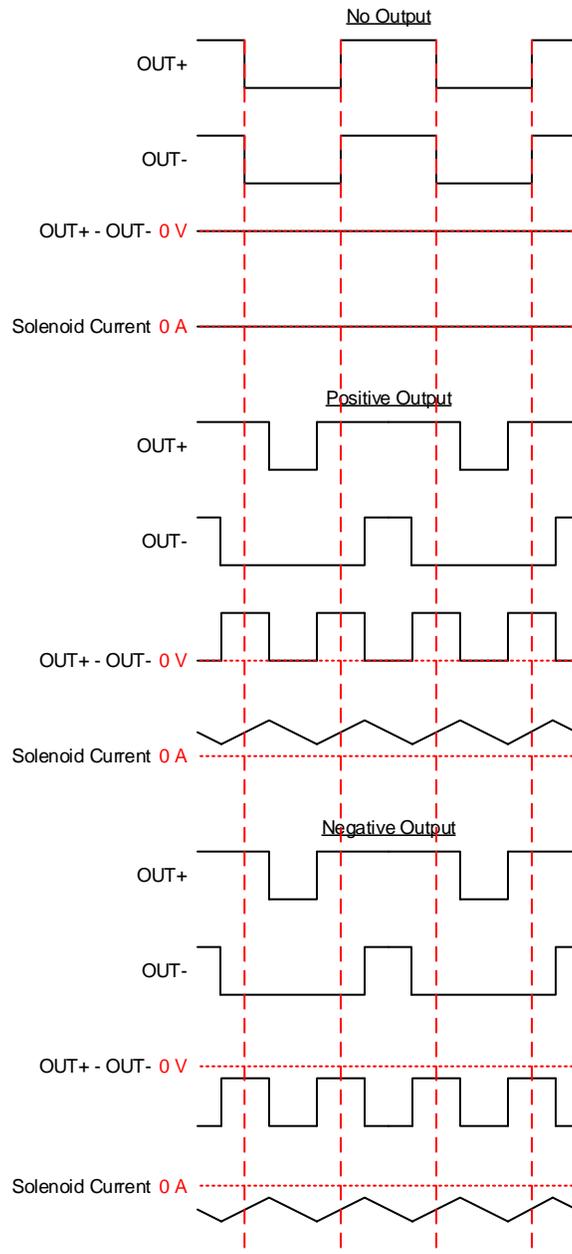


**Figure 3. Gain Configuration**

### 7.3.2 Pulse-Width Modulator (PWM)

The DRV2511-Q1 device features BD modulation scheme with high bandwidth, low noise, low distortion, and excellent stability.

The BD modulation scheme allows for smaller ripple currents through the load. Each output switches from 0 V to the supply voltage. With no input, the OUT+ and OUT- pins are in phase with each other so that there is little or no current in the load. For positive differential inputs, the duty cycle of OUT+ is greater than 50% and the duty cycle of OUT- is lower than 50% for a positive differential output voltage. The opposite is true for negative differential inputs. The voltage across the load sits at 0 V throughout most of the switching period, reducing the switching current, which reduces the  $I^2R$  losses in the load.



**Figure 4. BD Mode Modulation**

### 7.3.3 Designed for low EMI

The DRV2511-Q1 device design has minimal parasitic inductances due to the short leads on the package. This dramatically reduces EMI that results from current passing from the die to the system PCB. The design incorporates circuitry that optimizes output transitions that causes EMI. Follow the recommended design requirements in the [Design Requirements](#) section.

### 7.3.4 Device Protection Systems

The DRV2511-Q1 device features a complete set of protection circuits carefully designed to protect the device against permanent failures due to shorts, over-temperature, over-voltage, and under-voltage scenarios. The INTZ pin signals if an error is detected.

**Table 2. Fault Reporting Table**

FAULT	TRIGGERING CONDITION	INTZ	ACTION	LATCH?
Over-current	Output short or short to PVDD or GND	pulled low	output in high impedance	Latched
Over-temperature	$T_j > 150\text{ }^\circ\text{C}$	pulled low	output in high impedance	Latched
Under-voltage	$PVDD < 4.5\text{ V}$	-	output in high impedance	Self-clearing
Over-voltage	$PVDD > 27\text{ V}$	-	output in high impedance	Self-clearing

When the "Latched" conditions happen, the device must be reset with the EN signal in order to clear the fault. If automatic recovery from these conditions is desired, connect the INTZ pin directly to the EN pin. This allows the INTZ pin function to automatically drive the EN pin low which clears the latched condition.

## 7.4 Device Functional Modes

The DRV2511-Q1 device has multiple power states to optimize power consumption.

### 7.4.1 Operation in Shutdown Mode

The NRST pin of the DRV2511-Q1 device puts the device in a shutdown mode. When NRST is asserted (logic low), all internal blocks of the device are off to achieve ultra low power.

### 7.4.2 Operation in Standby Mode

The STDBY pin of the DRV2511-Q1 device puts the device in a standby mode. When STDBY is asserted (logic high), some internal blocks of the device are off to achieve low power while preserving the ability to wake up quickly to achieve low latency waveform playback.

### 7.4.3 Operation in Active Mode

The DRV2511-Q1 device is in active mode when it has a valid supply, and it is not in either shutdown or standby modes. In this mode the DRV2511-Q1 device is fully on and reproducing at the output the input times the gain.

## 7.5 Programming

### 7.5.1 Gain

The DRV2511-Q1 device has a configurable gain that is controlled through external resistors. Please see the Analog Input and Configurable Pre-amplifier section for more details.

## 8 Application and Implementation

### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

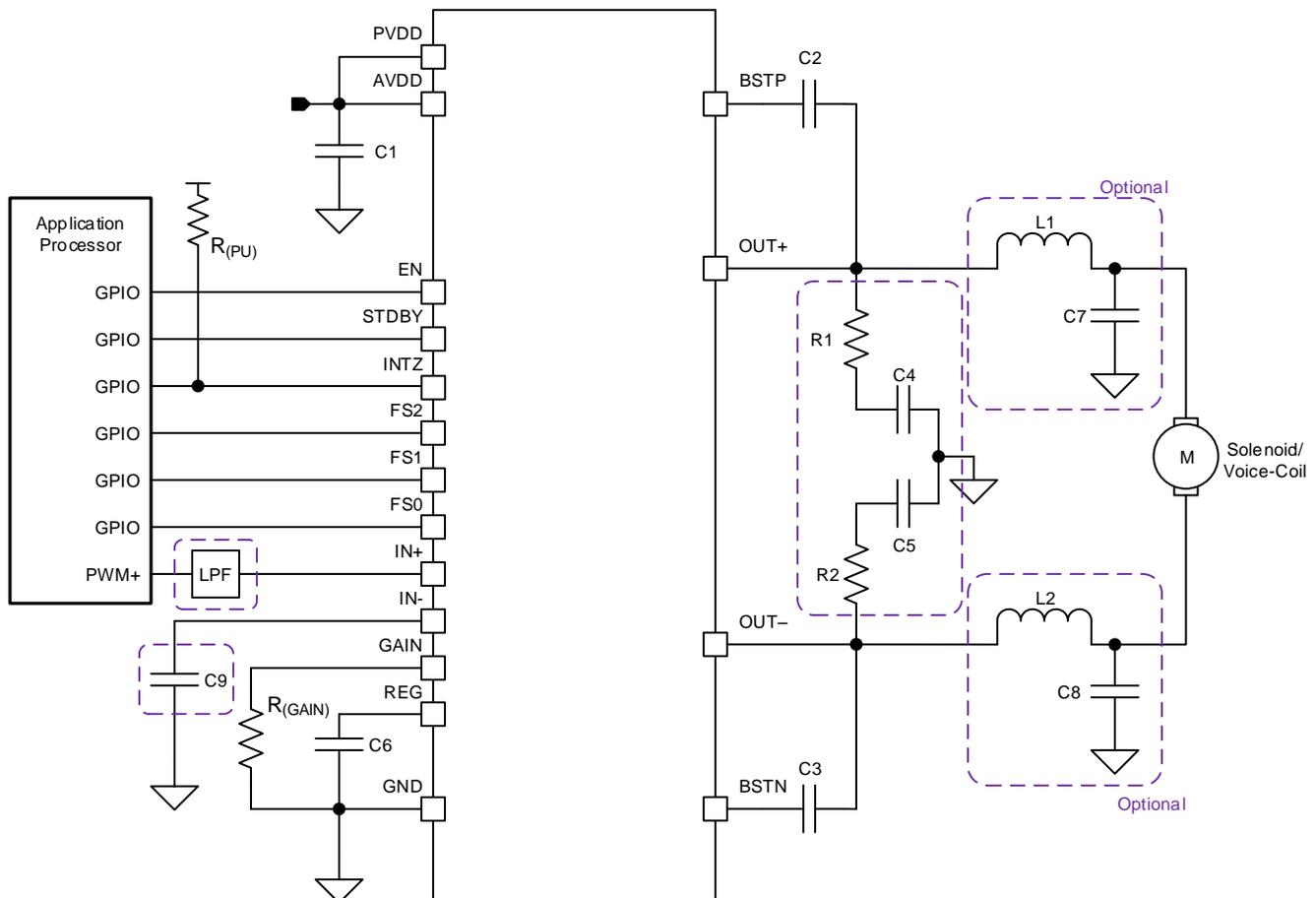
### 8.1 Application Information

The DRV2511-Q1 device is a high-efficiency driver for inductive loads, such as solenoids and voice-coils. The typical use of the device is on haptic applications where short, strong waveforms are desired to create a haptic event that will be coming from the application processor.

### 8.2 Typical Applications

#### 8.2.1 Single-Ended Source

To use the DRV2511-Q1 with a single-ended source, apply either a voltage divider to bias INB to 3 V, tie to GND or use a 0.1- $\mu$ F cap from INB to GND to have the device self bias. Apply the single-ended signal to the INA pin.



**Figure 5. Typical Application Schematic**

#### 8.2.1.1 Design Requirements

For most applications the following component values found in [Table 3](#) below can be used.

## Typical Applications (continued)

**Table 3. Component Requirements Table**

COMPONENT	DESCRIPTION	SPECIFICATION	TYPICAL VALUE
C1	Supply capacitor	Capacitance	22 $\mu$ F and 0.1 $\mu$ F for PVDD & AVDD
C2/C3	Boost capacitor	Capacitance	0.22 $\mu$ F
C4/C5	Output snubber capacitor	Capacitance	470 pF
C6	Regulator capacitor	Capacitance	1 $\mu$ F
C9	Input decoupling capacitor	Capacitance	0.1 $\mu$ F
R1/R2	Output snubber resistor	Resistance	3.3 $\Omega$
R <sub>(PU)</sub>	Pull-up resistor	Resistance	100 k $\Omega$

### 8.2.1.2 Detailed Design Procedure

#### 8.2.1.2.1 Optional Components

Note that in the diagrams, there are a few optional external components. These optional external components may be needed in the application to meet EMI/EMC standards and specifications by filters necessary frequency spectrums.

#### 8.2.1.2.2 Capacitor Selection

A bulk bypass capacitor should be mounted between VBAT and GND. The capacitance needs to be >22  $\mu$ F with a X5R or better rating on the power pins to GND. Also include two ceramic capacitors in the ranges of 220 pF to 1  $\mu$ F and 100 nF to 1  $\mu$ F. The bootstrap capacitors, BSTA and BSTB, should be 220-nF ceramic capacitors of quality X5R or better rated for at least the maximum rating of the pin.

#### 8.2.1.2.3 Solenoid Selection

The DRV2511-Q1 solenoid driver can accommodate a variety of solenoids. Solenoids should have an equivalent resistance of 1.6  $\Omega$  or greater. Solenoids with lower resistances are prone to driving high currents. A maximum peak current of 8-A should not be exceeded. The DRV2511-Q1 will go into a shutdown mode to protect itself from overcurrent.

#### 8.2.1.2.4 Output Filter Considerations

The output filter is optional and is mainly for limiting peak currents. A second-order Butterworth low-pass filter with the cut-off frequency set to a few kilohertz should be sufficient. See [Equation 2](#), [Equation 3](#), and [Equation 4](#) for example filter design.

$$H(s) = \frac{1}{s^2 + \sqrt{2}s + 1} \quad (1)$$

$$L_x = \frac{\sqrt{2} \times R_L}{2\omega_0} \quad (2)$$

$$2 \times C_F = \frac{\sqrt{2}}{2 \times \frac{R_L}{2} \times \omega_0} \quad (3)$$

$$\omega_0 = 2\pi \times f \quad (4)$$

### 8.2.1.3 Application Curves

These application curves were taken using an HA200 solenoid with a 100-g mass, and the acceleration was measured using the DRV-AAC16-EVM accelerometer. The following scales apply to the graphs:

- Output Differential Voltage scale is shown on the plots at 5-V/div
- Acceleration scale is 5.85-G/div
- Current scale is 2-A/div

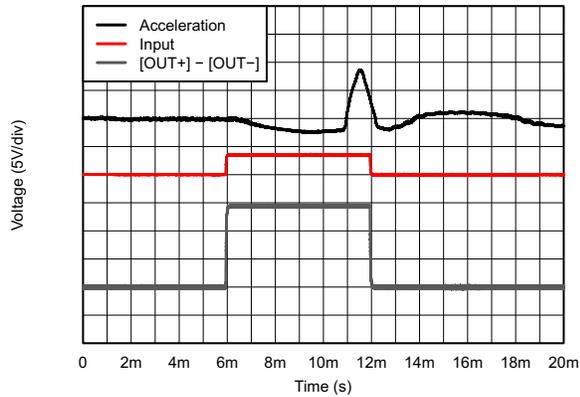


Figure 6. Voltage and Acceleration vs Time (Input Square Wave)

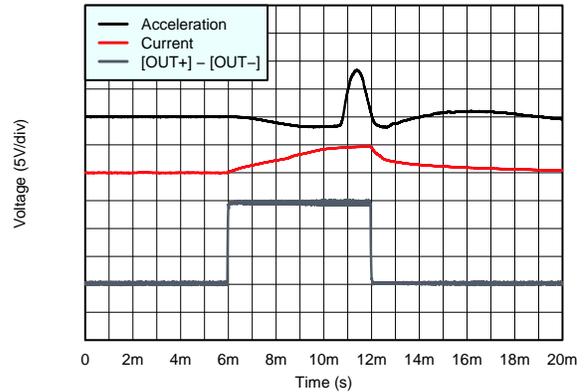


Figure 7. Voltage and Acceleration vs Time (Square Wave)

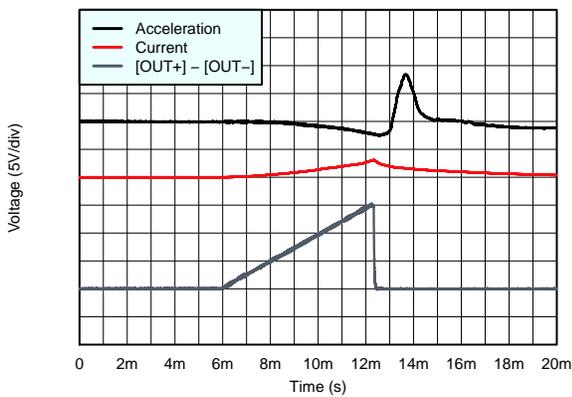


Figure 8. Voltage and Acceleration vs Time (Ramp Wave)

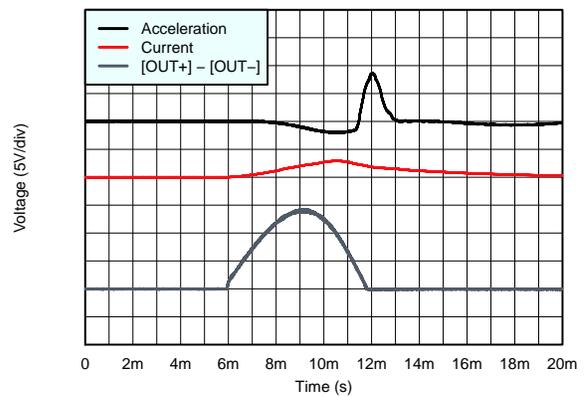


Figure 9. Voltage and Acceleration vs Time (1/2 Sine Wave)

### 8.2.1.4 Differential Input Diagram

To use the DRV2511-Q1 with a differential input source, apply both inputs differentially from a control source (GPIO, DAC, etc...).



## 9 Power Supply Recommendations

The DRV2511-Q1 device operates from 4.5 V - 26 V and this supply should be able to handle high surge currents in order to meet the high current draws for haptics effects. Additionally the DRV2511-Q1 should have 22- $\mu$ F and 0.1- $\mu$ F ceramic capacitors near the PVDD & AVDD pins for additional decoupling from trace routing.

## 10 Layout

### 10.1 Layout Guidelines

The EVM layout optimizes for thermal dissipation and EMC performance. The DRV2511-Q1 device has a thermal pad down, and good thermal conduction and dissipation require adequate copper area. Layout also affects EMC performance. It is best practice to use the same/similar layout as shown below in the DRV2511Q1EVM.

### 10.2 Layout Example

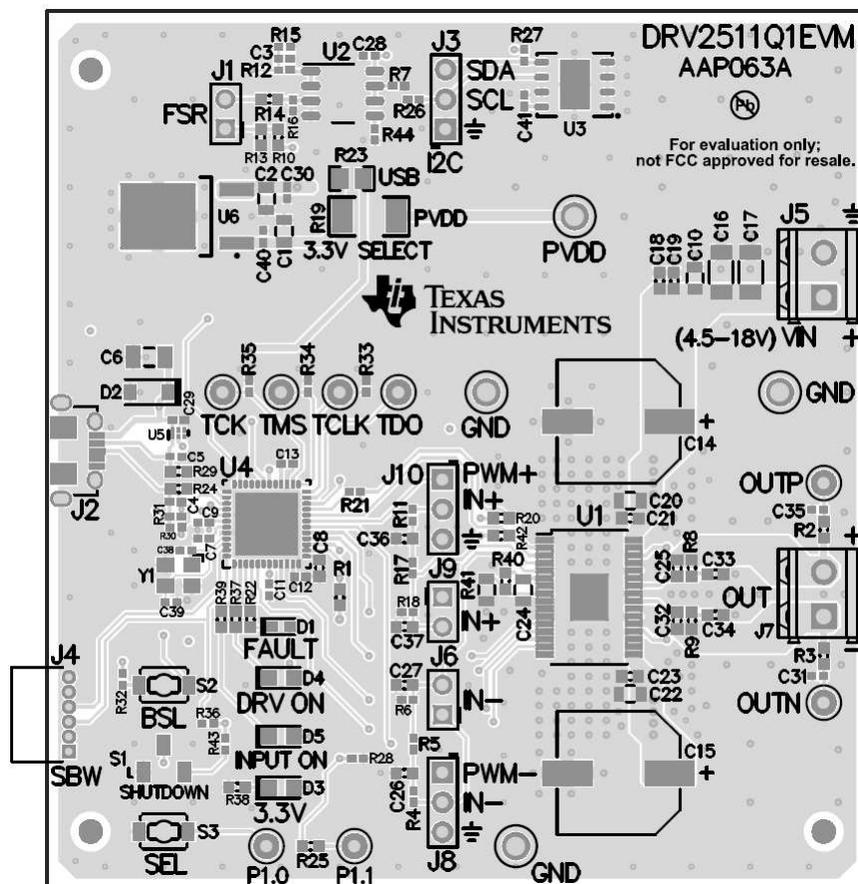


Figure 11. DRV2511-Q1 EVM

## 11 Device and Documentation Support

### 11.1 Device Support

#### 11.1.1 Third-Party Products Disclaimer

TI'S PUBLICATION OF INFORMATION REGARDING THIRD-PARTY PRODUCTS OR SERVICES DOES NOT CONSTITUTE AN ENDORSEMENT REGARDING THE SUITABILITY OF SUCH PRODUCTS OR SERVICES OR A WARRANTY, REPRESENTATION OR ENDORSEMENT OF SUCH PRODUCTS OR SERVICES, EITHER ALONE OR IN COMBINATION WITH ANY TI PRODUCT OR SERVICE.

#### 11.2 Trademarks

PowerPAD is a trademark of Texas Instruments.

#### 11.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### 11.4 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
DRV2511QDAPRQ1	ACTIVE	HTSSOP	DAP	32	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 125	DRV2511Q	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

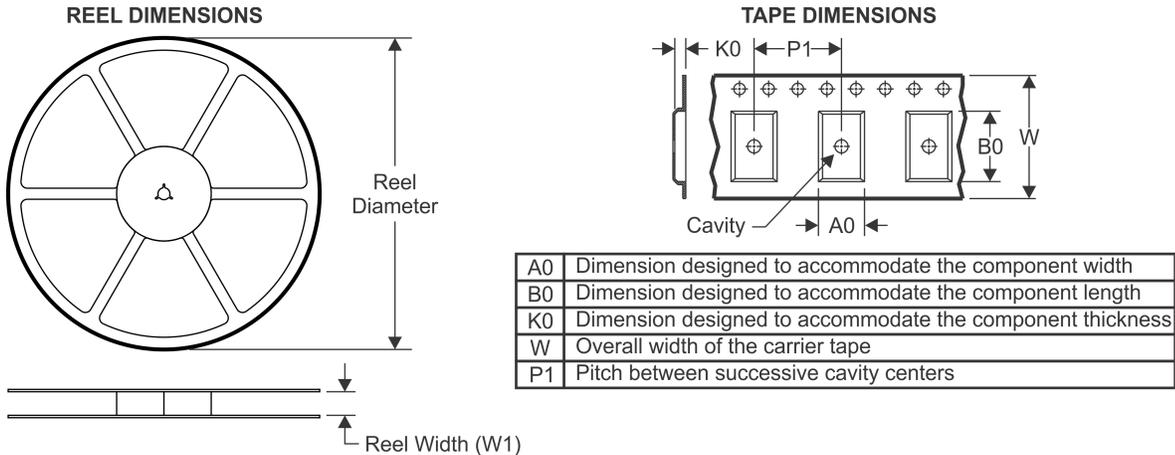
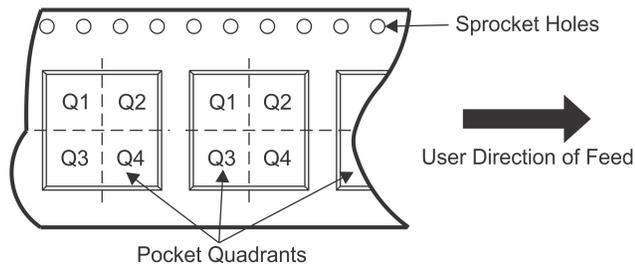
(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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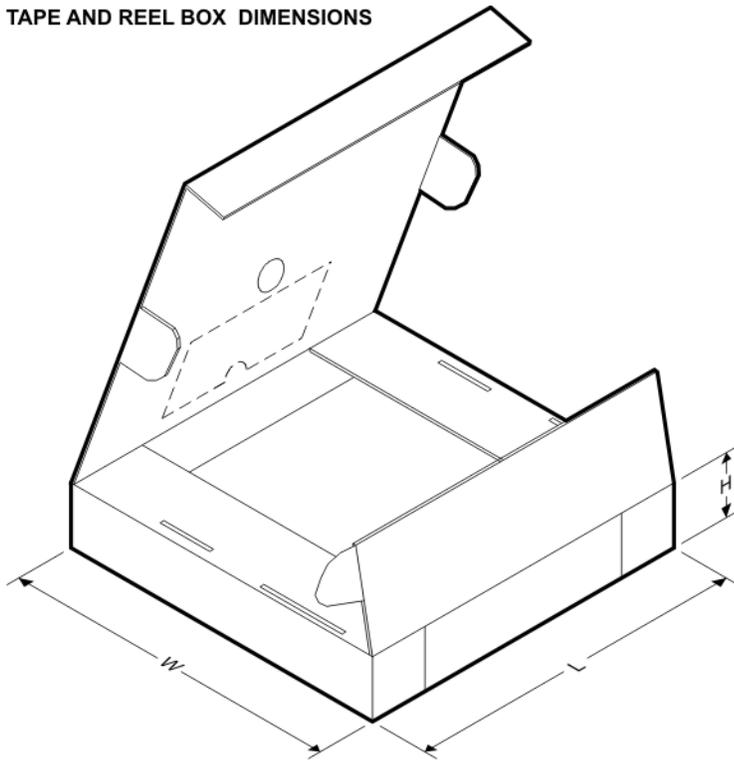


**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DRV2511QDAPRQ1	HTSSOP	DAP	32	2000	330.0	24.4	8.6	11.5	1.6	12.0	24.0	Q1

TAPE AND REEL BOX DIMENSIONS

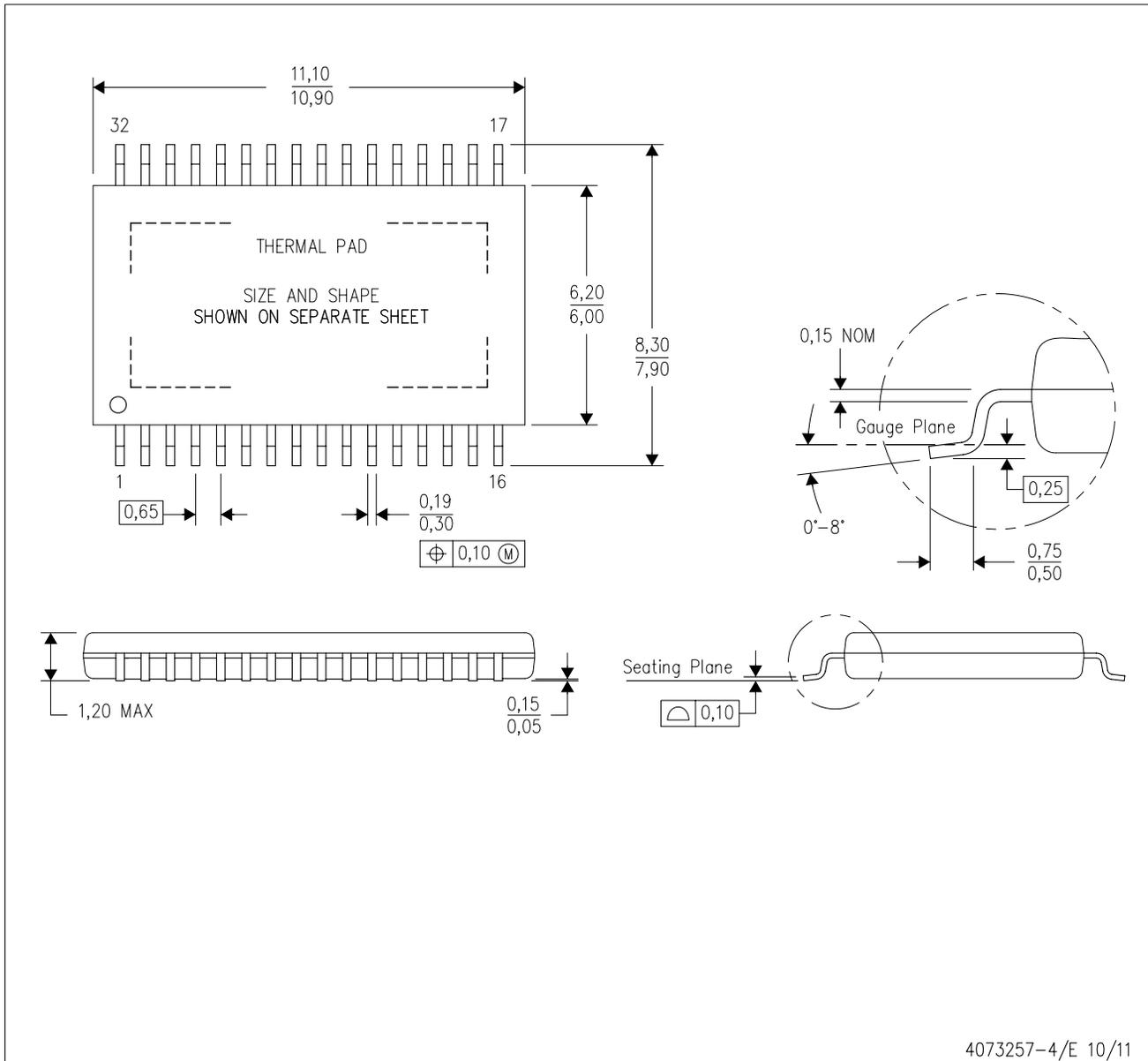


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DRV2511QDAPRQ1	HTSSOP	DAP	32	2000	367.0	367.0	45.0

# MECHANICAL DATA

DAP (R-PDSO-G32) PowerPAD™ PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
- $\triangle$  Falls within JEDEC MO-153 Variation DCT.

PowerPAD is a trademark of Texas Instruments.

# THERMAL PAD MECHANICAL DATA

DAP (R-PDSO-G32)

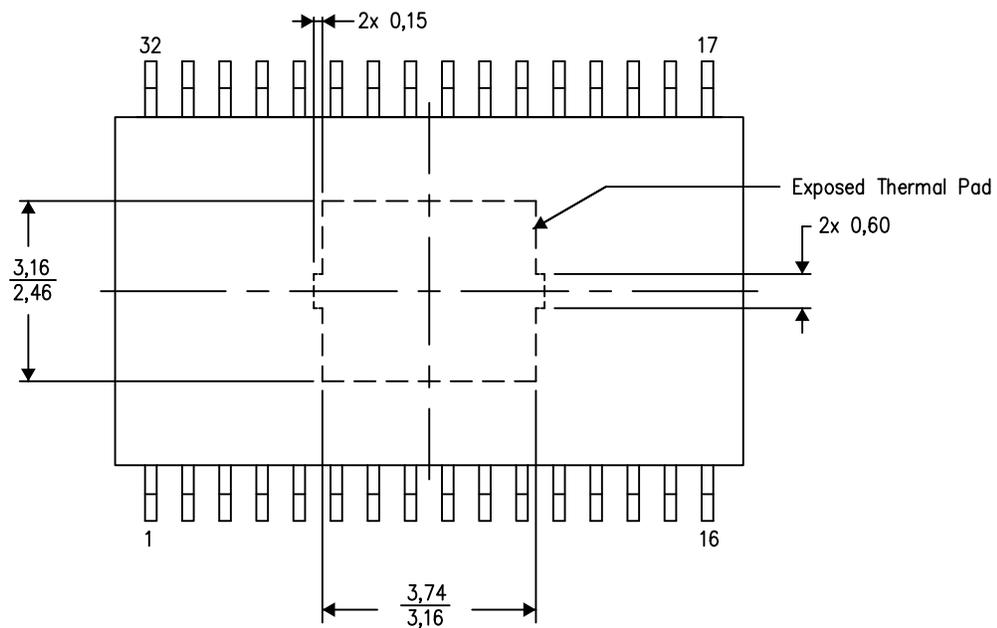
PowerPAD™ PLASTIC SMALL OUTLINE

## THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.



Top View

Exposed Thermal Pad Dimensions

4206319-12/M 09/13

NOTE: All linear dimensions are in millimeters

PowerPAD is a trademark of Texas Instruments.

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